

# 10A, 200V - 600V Super Fast Surface Mount Rectifier

#### **FEATURES**

- Very low profile, typical height of 1.1mm
- 175°C operating junction temperature
- Glass passivated chip junction
- Low conduction loss
- Low leakage current
- · High forward surge capability
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

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- DC to DC converter
- Switching mode converters and inverters
- Freewheeling application

#### **MECHANICAL DATA**

- Case: TO-277A (SMPC)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: Indicated by cathode band
- Weight: 0.095g (approximately)

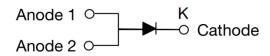
KEY PARAMETERS					
PARAMETER	VALUE	UNIT			
I <sub>F</sub>	10	Α			
$V_{RRM}$	200 - 600	V			
I <sub>FSM</sub>	150	Α			
$T_{JMAX}$	175	°C			
Package	TO-277A (SMPC)				
Configuration	Single die				







TO-277A (SMPC)



PARAMETER	SYMBOL	TPMR10D	TPMR10G	TPMR10J	UNIT
Marking code on the device		MR10D	MR10G	MR10J	
Repetitive peak reverse voltage	$V_{RRM}$	200	400	600	V
Reverse voltage, total rms value	V <sub>R(RMS)</sub>	140	280	420	V
Forward current	I <sub>F</sub>	10			Α
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I <sub>FSM</sub>	150			Α
Junction temperature	T <sub>J</sub>	-55 to +175			°C
Storage temperature	T <sub>STG</sub>	-55 to +175			°C



THERMAL PERFORMANCE						
PARAMETER	SYMBOL	TYP	UNIT			
Junction-to-lead thermal resistance <sup>(1)</sup>	$R_{\Theta JL}$	8.4	°C/W			
Junction-to-ambient thermal resistance <sup>(2)</sup>	$R_{\Theta JA}$	78	°C/W			

#### Notes:

- 1. Mounted on FR4 PCB with 16mm x 16mm Cu pad area
- 2. Free air, mounted on recommended pad

PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
	TPMR10D		· V <sub>F</sub>	-	0.95	V
	TPMR10G	I <sub>F</sub> = 10A, T <sub>J</sub> = 25°C		-	1.20	V
Forward voltage <sup>(1)</sup>	TPMR10J			-	1.80	V
Forward voltage <sup>(1)</sup>	TPMR10D			-	0.86	V
	TPMR10G	I <sub>F</sub> = 10A, T <sub>J</sub> = 125°C		-	1.00	V
	TPMR10J			-	-	V
	TPMR10D		I <sub>R</sub>	-	5	μA
	TPMR10G TPMR10J	T <sub>J</sub> = 25°C		-	10	μA
Reverse current @ rated V <sub>R</sub> <sup>(2)</sup>	TPMR10D			-	250	μA
	TPMR10G TPMR10J	T <sub>J</sub> = 125°C		-	500	μΑ
Junction capacitance		1MHz, V <sub>R</sub> = 4.0V	CJ	140	-	pF
	TPMR10D TPMR10G	IF = 0.5A, IR = 1.0A	t <sub>rr</sub>	-	35	ns
Payaraa raaayary tima	TPMR10J	Irr = 0.25A		-	40	ns
Reverse recovery time	TPMR10D TPMR10G	$I_F = 1A$ , di/dt = -50A/µs	t <sub>rr</sub>	-	60	ns
	TPMR10J	$V_R = 30V$		-	_	ns

#### Notes:

- 1. Pulse test with PW = 0.3ms
- 2. Pulse test with PW = 30ms

ORDERING INFORMATION					
ORDERING CODE <sup>(1)</sup>	PACKAGE	PACKING			
TPMR10x	TO-277A (SMPC)	6,000 / Tape & Reel			

#### Notes:

1. "x" defines voltage from 200V(TPMR10D) to 600V(TPMR10J)



### **CHARACTERISTICS CURVES**

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$ 

**Fig.1 Forward Current Derating Curve** 

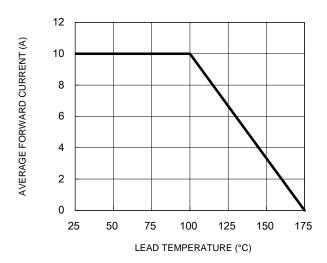


Fig.3 Typical Reverse Characteristics

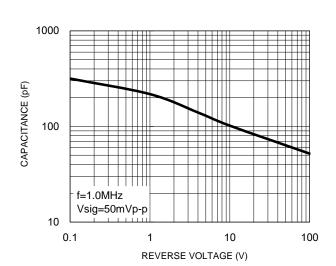
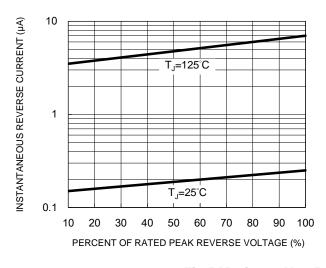


Fig.2 Typical Junction Capacitance

**Fig.4 Typical Forward Characteristics** 



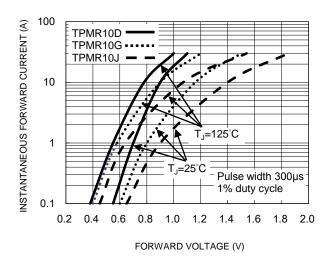
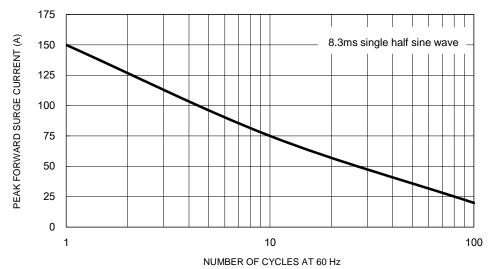


Fig.5 Maximum Non-Repetitive Forward Surge Current



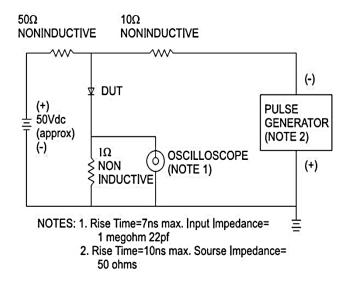
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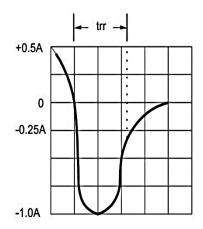


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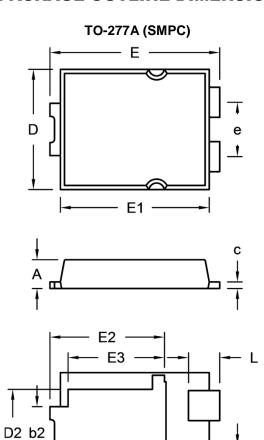
Fig.6 Reverse Recovery Time Characteristic and Test Circuit Diagram





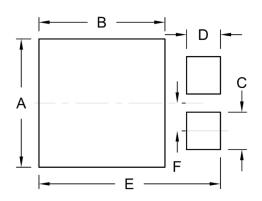


## **PACKAGE OUTLINE DIMENSIONS**



DIM.	Unit	(mm)	Unit (inch)		
	Min.	Max.	Min.	Max.	
А	1.000	1.200	0.039	0.047	
b	1.000	1.300	0.039	0.051	
b2	1.850	2.150	0.073	0.085	
С	0.175	0.325	0.007	0.013	
D	4.550	4.650	0.179	0.183	
D2	3.170	3.470	0.125	0.137	
E	6.350	6.650	0.250	0.262	
E1	5.650	5.750	0.222	0.226	
E2	4.235	4.535	0.167	0.179	
E3	3.540	3.840	0.139	0.151	
е	1.930	2.230	0.076	0.088	
L	1.043	1.343	0.041	0.053	

### **SUGGESTED PAD LAYOUT**



Symbol	Unit (mm)	Unit (inch)
Α	4.80	0.189
В	4.72	0.186
С	1.40	0.055
D	1.27	0.050
E	6.80	0.268
F	1.04	0.041

### **MARKING DIAGRAM**



P/N = Marking Code YW = Date Code F = Factory Code



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